Ashish Kumar Keshari, Male, Indian

DoB:November 26, 1976

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Career objective

To learn and work in an environment where I can get opportunity to show my abilities to achieve good results and come to the group expectation.

Areas of interest

- > Applied Physics/Condense Matter
- > Theoretical simulations on nanostructures
- > Growth, Characterization and application of Electronic/Opto-electronic Materials, Semiconductors
- > Development and Application of Nanotechnology for molecular/nano-electronics, Spintronics, electro-optical devices, Solid State Lighting (SSL), Solar Cell, Display technology and for Biomedical applications
- > Growth, Characterization and Application of Nanophosphorescence Materials
- > Organic Electronics (OLED)
- > LED design and fabrication, , Nanocrystals Imaging Systems
- > Materials Characterization with XRD, SAXS, HRTEM, SEM, EDAX, SPM/AFM/STM, Nano-indentor, Raman spectroscopy, Transport Measurements, UV-Vis Absorption Spectroscopy, Photoluminescence spectroscopy, NSOM, DTA/TGA/TMA.

Experience summery

- 1. **February 13, 2010 Till date : Research/Faculty Associate** at School of Engineering, Gautam Buddha University, Grater Noida-201308 (Responsibilities: Courses design, Developments of Labs, Teaching, Research, academic and other administrative responsibilities)
- **2.** March **29, 2005** to March **31, 2009**: Scientist at Nanophosphor Application Centre, Faculty of Science, University of Allahabad, Allahabad 211002. (Responsibilities: Facility development, Application of instruments in characterizing nanostructured materials, Synthesis & Characterization of Nanophosphors/Semiconductor Nanocrystals (Quantum Dots)) /Conjugates of QDs with organic/bio-molecules for Nanoelectronics, Opto-electronics Devices, Solid State Lighting, Display Technology and for Biomedical Applications), Advisor: Dr. Avinash C. Pandey
- **3. August 2004 to February 2005**: Institute Fellowship at IIT Kanpur, Kanpur 208016. (Responsibilities: Design and Characterization of organic light emitting diodes) Lab: SAMTEL CENTER FOR DISPLAY TECHNOLOGIES, Advisor: Prof. Y. N. Mohapatra

Research papers

- 1. International referred journals 7 (published), 2 (submitted)
- 2. Conferences/Symposia/Workshop 11 (paper presented), 4 (participated)

Education summery

- 1. Ph.D. in Science from University of Allahabad, India (Submitted in October 7, 2009), Thesis: Quantum Confined Atom based Nanomaterials for their Application in Electronics, Opto-electronic Devices and in Biology, Advisor: Dr. Avinash C. Pandey (Department of Physics, University of Allahabad)
- **2.** M.Tech. (1st with Honors) in Materials Science and Technology department at Institute of Technology, BHU, Varanasi, India (Year 2004)

CGPA: 8.33/10 or 83.3%

Thesis: Design of a Microwave absorber in X-band having wedge-tapered absorber arrays with coating of resin-ferrite composite.

Advisor: Prof.B R Vishvakarma (Dept. of Electronics Engg., IT-BHU, Varanasi)

Project: Design & Characterization of (Ba, Sr) TiO3 based Capacitors.

Advisor: Prof. Dhananjai Pandey/Dr. Rajiv Ranjan (School of Materials Science & Technology,

IT-BHU, Varanasi)

3. M.Sc. in Physics (Gold Medalist, 1^{st} divison) with specialization in Electronics from University of Allahabad, Allahabad, India (Year 2001)

Scholastic Average: 68.55%

4. Bachelor in Science (PCM) from University of Allahabad (1999)

TECHNICAL SKILLS

- **1. Instruments Handling**: Rigaku X-ray Diffractometer (**SAXS & WAXS**), Electron microscopy (Tecnai G² 30 and FEI Quanta 200), SPM (Nanonics Imaging), Photoluminescence spectroscopy (Perkin Elmer), UV-Vis absorption spectroscopy (Perkin Elmer), Raman spectroscopy (Renishaw), Nano-indentor (CSM Instruments), DTA/TGA /TMA (Perkin Elmer) etc. Vacuum Coating Units, Patterning of ITO, OLED design and fabrication, Spin coating unit, Homogenizer, Ultracentrifuge, Working experience in class 1000 clean room and in Lithography lab.
- 2. Diploma in Computer Programming and System Applications

DOS, Windows 2000/XP, Linux, MS-Office, LAN, dBASE, FoxPro, C/C++, Internet

ACADEMIC ACCOMPLISHMENTS

- **1. Received two Gold-Medals** for securing highest marks in M.Sc final and M.Sc electronics branch respectively.
- **2.** Participated in '4th Advanced School on Nanoscience and Technology' on 'Nanolithography' during January 12-24, 2009 at S.N. Bose National Centre for Basic Sciences, Kolkata sponsored by DST, India
- 3. GATE score: 93.19 percentile (136 all India rank), AICTE, MHRD Scholarship (2002-2004)
- **4. Vice-president** of Physics society at University of Allahabad (2008-09)

REFERENCES

Dr. R. N. Bhargava **Prof. Avinash C. Pandev** Dr. R. J. Choudhary Nanocrystals Technology Principal Investigator Sr. Scientist P.O.Box 820, Briarcliff Manor Nanotechnology Application Centre, **UGC-DAE** Consortium for Scientific Research Department of Physics University Campus, NY10510 USA University of Allahabad Khandwa Road, Indore Allahabad – 211002, India. ramjanay@gmail.com Fax/Tel: +91-532-2460675 Mobile:+91-9893849446 rbhargava@nanocrystals.com www.nanocrystals.com dr.avinashcpandey@gmail.com

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